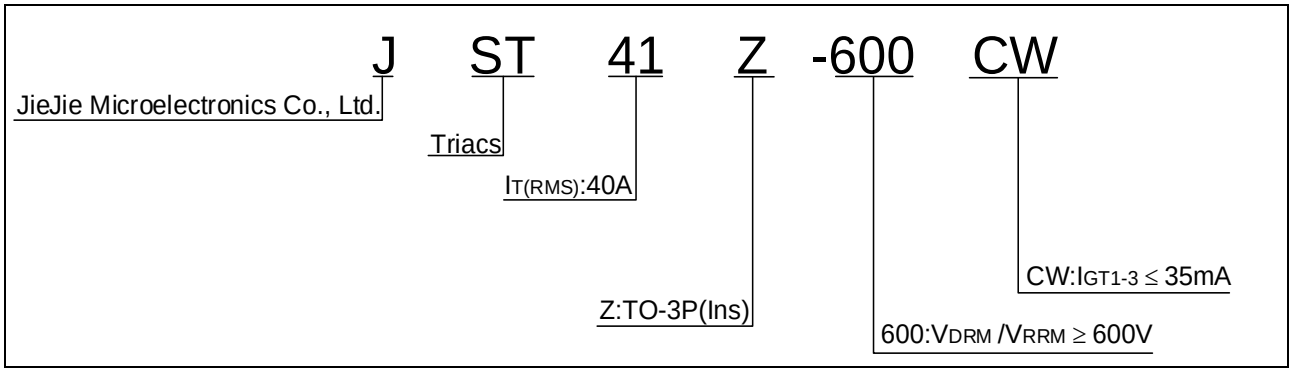
Average gate power dissipation (T_j=125)	$P_{G(AV)}$	0.5	W
Peak gate power	P_{GM}	40	W

Peak pulse voltage
(T_j=25 ; non-

ORDERING INFORMATION



MARKING

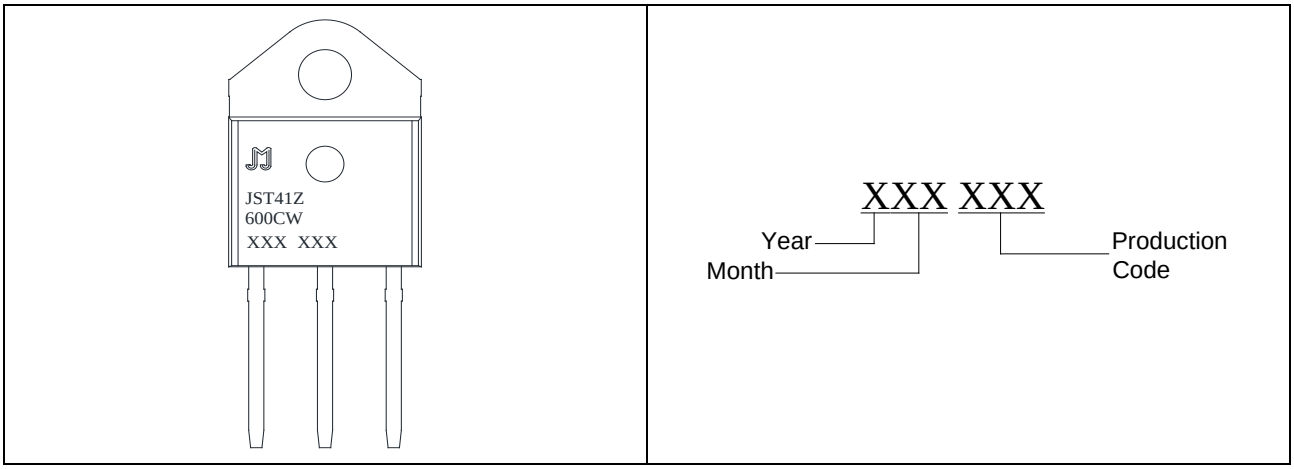


FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2: Stat e cur -18.4 (ent)6.3 vaxursse cs

ORDERING INFORMATION

Order code	Voltage V_{DRM}/V_{RRM}(V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST41Z-600CW	600	35	TO-3P(Ins)	30	Tube

Document Revision History

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated
Oct.16, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



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